# Amplifiers: pumping and small-signal gain

- Absorption  $I[z] = I_0 \exp[-N_0 \sigma_{12} z] = I_0 \exp[-\alpha z]$
- Gain  $I[z] = I_0 \exp[N_{inv}\sigma_{21}z] = I_0 \exp[gz]$ 
  - What is the inversion density?
  - How to express it in terms of the pump distribution
  - How does gain depend on  $\lambda$  or  $\omega$  ?
  - What happens when the inversion density is depleted?





#### Simple gain calculation

- Assume uniform pump distribution  $G_0 = \exp[N_{inv}\sigma_{21}L]$  Small-signal gain
- Available energy for extraction:

$$E_{stor} = N_{inv} A L h V_{21} \rightarrow N_{inv} = \frac{E_{stor}}{A L h V_{21}}$$

A = area of beam

$$G_0 = \exp\left[\frac{E_{stor}}{A}\frac{\sigma_{21}}{hv_{21}}\right]$$

- Energy fluence = energy per unit area
- Define:
  - "stored fluence"

- "saturation fluence"

$$\Gamma_{stor} = \frac{E_{stor}}{A}$$

 $\sigma_{_{21}}$ 

**I**<sub>sat</sub>

$$_{0} = \exp\left[\frac{\Gamma_{stor}}{\Gamma_{sat}}\right]$$

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#### **Example: Ti:sapphire amplifier**

Pump laser has 10mJ per pulse, calculate spot size in crystal for G<sub>0</sub> = 5

Ti:sapphire:

- $\lambda_{21}$ =800nm, hv = 1.55eV = 2.48x10<sup>-19</sup> J
- $-\sigma_{21} = 2.8 \text{ x } 10^{-19} \text{ cm}^2$
- $-\Gamma_{sat} = 0.85 \text{ J/cm}^2$



$$\Gamma_{\text{stor}} = \Gamma_{\text{sat}} \ln[G_0] = 1.37 \text{ J/cm}^2$$

 $A = 7.3 \times 10^{-3} \text{ cm}^2$ 

 $w_0 = 480 \text{ um}$ 

For pulse duration of 10ns, pump intensity is

 $I = 1.37 \times 10^8 \text{ W/cm}^2$ 

### Optical pumping geometries

Technique depends on properties of light source

- Diffuse:
  - flashlamp, arc lamp (CW), LED sun
  - Pump chambers, non-imaging concentrators
- Laser beams with poor divergence:
  - laser diode elements and arrays, multi-mode fibercoupled LDs
  - Longitudinal and side pumping
- High-quality laser beams
  - Longitudinal pumping



Fig. 6.47. Major pump configurations a) side pumping with flashlamps, b) side-and edge pumping with laser diodes, c) end pumped lasers, d) face pumping with flashlamps or laser diodes.

#### **Population dynamics of absorption**

• Closed 2 level system, assume  $g_1 = g_2$   $\frac{dN_1}{dN_2}$ 

• Since system is closed, reduce to one equation for population difference:  $\Delta N = N_1 - N_2$   $N_t = N_1 + N_2$ 

$$\frac{dN_1}{dt} - \frac{dN_2}{dt} = \frac{d}{dt}\Delta N = -2\frac{dN_2}{dt} \qquad \qquad N_t = \Delta N + 2N_2$$

$$\frac{d}{dt}\Delta N = -2\left(W\Delta N - A_{21}N_2\right)$$

$$\frac{d}{dt}\Delta N = -2W\Delta N + A_{21}\left(N_t - \Delta N\right) = -\Delta N\left(A_{21} + 2W\right) + A_{21}N_t$$

$$- \text{ Steady state:} \qquad \Delta N = \frac{N_t}{1 + 2W\tau_{21}} \qquad A_{21} = 1/\tau_{21}$$

#### Saturation of absorption

- The key parameter in this situation is W  $T_{21}$ 
  - $W_{21} = \rho_v B_{21}$
  - Low intensity, 2W  $T_{21} \ll 1$ ,  $\Delta N \approx N_t$
  - High intensity, 2W  $\tau_{21}$  >> 1,  $\Delta$ N ≈ 0. Here N<sub>1</sub> ≈ N<sub>2</sub>
- Energy balance:

Input power (into 4π) Absorbed by atoms

Stimulated emission ( back into beam)

• Radiated power per unit volume:

$$\frac{dP}{dV} = hV_{21}W\Delta N(W) = hV_{21}\frac{N_tW}{1+2W\tau_{21}} \to hV_{21}\frac{N_t}{2\tau_{21}} \quad \text{For W } \tau_{21} >> 1$$

Power radiated in high intensity limit: half of atoms are radiating

$$\Delta N = \frac{N_t}{1 + 2W\tau_{21}}$$

$$\Delta N = N_1 - N_2$$

#### Saturation intensity

- Absorbed power per atom:  $\sigma_{12}I$
- Absorption rate: Absorption rate:  $W = \frac{1}{hv_{21}}$ • In steady state:  $\frac{\Delta N}{N_t} = \frac{1}{1+2W\tau_{21}} = \frac{1}{1+2\frac{\sigma_{12}I}{hv_{21}}\tau_{21}} = \frac{1}{1+2\frac{\sigma_{12}I}{hv_{21}}\tau_{21}}$
- Saturation intensity for absorption:
  - 2: transition affects both levels at once  $I_{sat}$
  - At I =  $I_{sat}$ , stimulated and spontaneous emission rates are equal.
- Intensity-dependent absorption coefficient:

$$\alpha(I) = \frac{\alpha_0}{1 + I/I_{sat}}$$

At high intensity, material absorbs less.

Saturable absorbers are used for pulsed lasers: Q-switching and mode-locking

# Saturated CW propagation through absorbing medium

 For a given thickness for an absorbing medium, the transmission will increase with intensity



# **Pulsed input: saturation fluence** $\Delta N = N_1 - N_2$

Rewrite equation using intensity:

$$\frac{d}{dt}\Delta N = -\Delta N \left( A_{21} + \frac{2\sigma}{hv_{21}} I(t) \right) + A_{21}N_t \equiv -\Delta N \left( A_{21} + \frac{I(t)}{\Gamma_{sat}} \right) + A_{21}N_t$$

- Scaling of equation
  - Two timescales:  $\tau_p$  and  $\tau_{21}$ , but pay attention to weighting  $d_{AN} = AN \begin{pmatrix} 1 & \Gamma_{in} & 1 \end{pmatrix} + \begin{pmatrix} 1 & N & 2N_2 & \Gamma_{in} & 1 \\ N & N & N \end{pmatrix}$

$$\frac{d}{dt}\Delta N = -\Delta N \left(\frac{1}{\tau_{21}} + \frac{1}{\Gamma_{sat}}\frac{1}{\tau_p}\right) + \frac{1}{\tau_{21}}N_t = \frac{2N_2}{\tau_{21}} - \frac{1}{\Gamma_{sat}}\frac{1}{\tau_p}\Delta N$$

• For short pulse input: ignore stimulated emission and fluorescence

$$\frac{\Gamma_{in}}{\Gamma_{sat}} \frac{1}{\tau_p} |\Delta N| \gg \frac{2N_2}{\tau_{21}} \longrightarrow \frac{d}{dt} \Delta N \approx -\frac{\Gamma_{in}}{\Gamma_{sat}} \frac{1}{\tau_p} \Delta N \longrightarrow \ln\left[\frac{\Delta N(t)}{\Delta N(0)}\right] \approx -\frac{1}{\Gamma_{sat}} \int_0^t I(t') dt'$$
$$\longrightarrow \Delta N(t) = N_1(t) - N_2(t) \approx N_t \exp\left[-\frac{1}{\Gamma_{sat}} \int_0^t I(t') dt'\right] = N_t \exp\left[-\frac{\Gamma_{in}}{\Gamma_{sat}}\right]$$

# Short pulse limit

- For short pulse input:  $T_p << T_{21}$ , so ignore fluorescence
  - Medium just integrates energy of pulse.
  - Example: Ti:sapphire: τ<sub>21</sub>=3.2µs, τ<sub>p</sub>=10ns or 200ns for Q-switched Nd:YAG lasers pumped with flashlamps or CW arc lamps
- Square input pulse Gaussian input pulse

 $-\tau = 3$ ,  $I_{0/}I_{sat} = 0.1$ , (no fluorescence)



Shape of transmitted pulse is affected

## Long pulse limit

 For *long* pulse input: τ<sub>p</sub>>>τ<sub>21</sub>, and peak I << I<sub>sat</sub>, ΔN(t) follows I(t)

 $\rightarrow \frac{d}{dt} \Delta N \ll A_{21} N_t$  $\frac{\Delta N}{N_t} = \frac{1}{1 + I(t)/I_{sat}}$ 

Quasi-static, quasi-CW limit N<sub>t</sub> adiabatically follows I(t)



#### **Gain saturation**

• Consider a 4-level system:



No factor of 2  $I_{sat} = \frac{hv_{21}}{\sigma_{21}\tau_{21}} = \frac{\Gamma_{sat}}{\tau_{21}}$  $g(I) = \frac{g_0}{1 + I/I}$ 

#### **Beam growth during amplification**

Calculation just as with absorption

$$\int_{I_0}^{I} \left(\frac{1}{I} + \frac{1}{I_{sat}}\right) dI = + \int_{0}^{L} g_0 \, dz \rightarrow \ln\left[\frac{I(z)}{I(0)}\right] + \frac{I(z) - I(0)}{I_{sat}} = + g_0 z$$
Net gain over 1 absorption length
$$\int_{I_0}^{I_0} \frac{1}{I_{sat}} = 0.1$$

$$\int_{I_0}^{I_0} \frac{1}{I_{sat}} = 0.1$$

$$\int_{I_0}^{I_0} \frac{1}{I_{sat}} = 10$$

Even though saturated gain is low, it is efficient at extracting stored energy

# **Spatial dependence**

- Gain follows distribution of pump intensity
- Spatial variation of gain affects beam profile
- Examples:
  - Iongitudinal pumping with Gaussian beam leads to gain narrowing of spatial profile. More gain in center, less at edges
  - Saturated absorption by a Gaussian beam: saturation in center suppresses intensity there. Leads to widening of output beam.

#### Pulse amplification: saturated gain algorithm



## Example: Ti:sapphire multipass amp

- Seed pulse from pulsed laser oscillator: 1nJ (800nm)
- Amplify to 1mJ, use 7mJ of pump energy (532nm)
- Multipass designs: spatially separate beams

#### **Three-mirror ring preamp:**

- Up to 12 passes
- Focused beam in crystal
- 2 mirror alignment

# Q-switched Nd;YLF IOW max IOW max III (Sapphire Pulses input)

#### **Bowtie power amp:**

- Collimated beam
- 8 mirrors



#### **Multipass design**

- Assume uniform pumping with round beams
- Calculate stored fluence and small signal gain
- Use saturated gain expression to calculate new energy after 1<sup>st</sup> pass
- Subtract extracted energy from stored energy (over seed spot area)
- Repeat for N passes

Conditions: 1nJ seed, 7mJ pump energy, 95% absorption, 10% loss/pass Stored energy:  $hV_{mad}$ 

$$E_{stor} = E_{pump} \eta_{abs} \frac{h v_{seed}}{h v_{pump}} = 4.4 \, mJ$$

Small signal gain estimate:

$$G_0 = \left(\frac{E_{\text{target}}}{E_{\text{seed}}}\right)^{1/N} \frac{1}{1-L} = 4.42$$

Estimated spot size:

$$A_{pump} = \frac{E_{stor}}{\Gamma_{sat} \ln[G_0]}, \quad w_p = 300 \,\mu m$$

#### **Multipass: Simple calculated results**

 Small signal gain estimate works as long as stored energy is not depleted



- Smaller seed size to ensure full overlap with pump
- Avoid damage thresholds for pump and seed
- Saturate at desired energy to reduce noise
- Account for size change in Brewster cut crystal



# Polarization issues in pumping birefringent materials

- For Ti:sapphire, both polarizations contribute to seed gain along c-axis
- Much higher pump absorption for E along c-axis

 $- \alpha$  across c-axis is about 40% lower than along c-axis



# **Transverse Pumping Gain Estimates**

- Seed: 2nJ
  - Cavity Losses: ~1%
  - т<sub>pass</sub>: 1ns
- Pump (CW): 1kW (Total: 2X .5kW Bars)
  - η<sub>Abs</sub>=63.2%
  - η<sub>QD</sub>=55.6%
  - $-\eta_{Pump} = \eta_{Abs} \eta_{QD} = 35.1\%$
  - − Heat: ~560 W
  - Significant (Cylindrical) Thermal Lens Expected
  - w=30um
- Single Pass Gain (small signal)
  - Astigmatic Seed: g≈1.64
    - w<sub>x</sub>=200um, w<sub>y</sub>=30µm
  - Spatially Chirped Seed: g≈1.64
    - w<sub>x</sub>=2mm, w<sub>y</sub>=30µm

•Multi-Pass Extraction: 37 Passes

-Astigmatic Mode: ~136uJ (small extraction area) -Spatially Chirped:~.53mJ (46% extraction)

Central dip in gain: spatial gain mode *expansion*. This could be used to counter gain narrowing for spatially-chirped seed



# Frequency dependence: account for lineshapes

• Absorption and gain coefficients and saturation intensity both depends on frequency

$$\alpha(I,v) = \frac{\alpha_0(v-v_0)}{1+\frac{I(v)}{I_{sat}(v-v_0)}}$$

- For broadband input, saturation changes shape of transmitted spectrum
  - Absorption: power broadening
  - Gain: spectral gain narrowing

# **Amplified Spontaneous Emission (ASE)**

- Spontaneous emission is emitted into 4π steradians, but is amplified on the way out if there is gain.
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    - ASE can be considered to be a noise source
    - ASE is more directional than fluorescence, but not as directional as a coherent laser beam
    - Some high-gain lasers are essentially ASE sources (no mirrors)
- Implications for amplifier design
  - ASE can deplete stored energy before pulse extraction
  - Use timing and good seed energy to extract energy from medium before ASE
  - Ensure that transverse gain is smaller than longitudinal to avoid parasitic depletion.

# Self-absorption and "optically-thick" media

- A related phenomenon for an absorbing medium is when radiation is *absorbed* along the way out.
- More absorption near the line center, so the transmitted light is broader in spectrum.
- For an extended luminous body (e.g. the Sun), the individual spectral lines get merged together to look like the blackbody.